

SEMICONDUCTOR®

KSA1281

Audio Power Amplifier

- Collector Power Dissipation : $P_C=1W$
- 3 Watt Output Application



1. Emitter 2. Collector 3. Base

PNP Epitaxial Silicon Transistor

Absolute Maximum	Ratings $T_a=25^{\circ}C$ unless otherwise noted
------------------	---

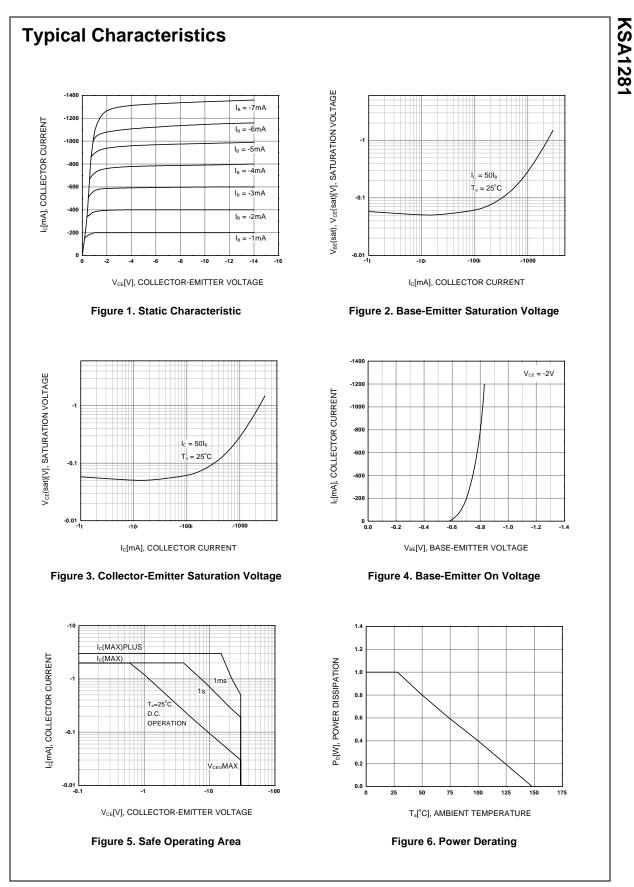
Symbol	Parameter	Ratings	Units	
V _{CBO}	Collector-Base Voltage	-50	V	
V _{CEO}	Collector-Emitter Voltage	-50	V	
V _{EBO}	Emitter-Base Voltage	-5	V	
I _C	Collector Current	-2	Α	
P _C	Collector Power Dissipation	1	W	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-55 ~ +150	°C	

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	mbol Parameter Test Condition		Parameter Test Condition		Min.	Тур.	Max.	Units	
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = -100, I _E =0	-50			V			
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = -10mA, I _B =0	-50			V			
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = -1mA, I _C =0	-5			V			
I _{CBO}	Collector Cut-off Current	V _{CB} = -50V, I _E =0			-100	nA			
I _{EBO}	Emitter Cut-off Current	V _{EB} = -5V, I _C =0			-100	nA			
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} = -2V, I _C = -500mA V _{CE} = -2V, I _C = -1.5A	70 40		240				
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C = -1A, I _B = -0.05mA			-1.2	V			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -1A, I _B = -0.05mA			-0.5	V			
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0, f=1MHz		40		pF			
f _T	Current Gain Bandwidth Product	V _{CE} = -2V, I _C = -500mA		100		MHz			

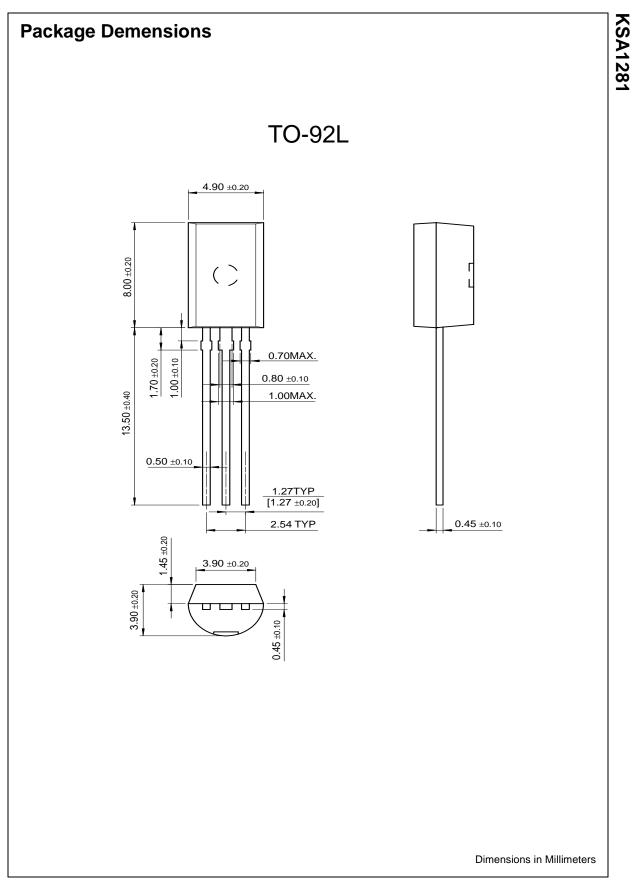
h_{FE1} Classification

Classification	0	Y		
h _{FE1}	70 ~ 140	120 ~ 240		



©2001 Fairchild Semiconductor Corporation

Rev. A1, June 2001



TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACExTM BottomlessTM CoolFETTM $CROSSVOLT^{TM}$ DenseTrenchTM DOMETM EcoSPARKTM E^2CMOS^{TM} EnSignaTM FACTTM FACT Quiet SeriesTM FAST[®] FASTr[™] FRFET[™] GlobalOptoisolator[™] GTO[™] HiSeC[™] ISOPLANAR[™] LittleFET[™] MicroFET[™] MICROWIRE[™] OPTOLOGIC[™]

OPTOPLANAR™ PACMAN™ POP™ Power247™ PowerTrench[®] QFET™ QS™ QT Optoelectronics™ Quiet Series™ SLIENT SWITCHER[®] SMART START™ STAR*POWER[™] Stealth[™] SuperSOT[™]-3 SuperSOT[™]-6 SuperSOT[™]-8 SyncFET[™] TruTranslation[™] TinyLogic[™] UHC[™] UltraFET[®] VCX[™]

STAR*POWER is used under license

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Fairchild Semiconductor		sSEARCH <u>Parametric</u> <u>Cross Reference</u>		
		space Produc	t Folders and Annlica	
find products	Home >> Find products >>			
Products groups	KSA1281 PNP Epitaxial Silicon Transistor		Related Links	
<u>Analog and Mixed</u> <u>Signal</u> <u>Discrete</u> Interface	Contents Features Product status/pricing/packaging	Datasheet Download this datasheet	Request samples Dotted line How to order products Dotted line	
Logic Microcontrollers Non-Volatile	Features	PDF	Product Change Notices (PCNs) Dotted line Support	
<u>Memory</u> <u>Optoelectronics</u> <u>Markets and</u>	Audio Power Amplifier	<u>e-mail this datasheet</u> • <u>[E-</u>	 Dotted line Distributor and field sales representatives 	
applications New products Product selection and	 Collector Dissipation : P_C = 1W 3 Watt Output Application 	This page <u>Print version</u>	Dotted line Quality and reliability Dotted line Design tools	
parametric search Cross-reference	back to top			

-

search

buy products

my Fairchild

company

technical support

technical information

Product status/pricing/packaging

Ī	Product	Product status	Pricing*	Package type	Leads	Packing method
4	KSA1281OBU	Full Production	\$0.098	TO-92	3	BULK
4	KSA1281YBU	Full Production	\$0.098	TO-92	3	BULK

* 1,000 piece Budgetary Pricing

back to top

<u>Home</u> | <u>Find products</u> | <u>Technical information</u> | <u>Buy products</u> | <u>Support</u> | <u>Company</u> | <u>Contact us</u> | <u>Site index</u> | <u>Privacy policy</u>

© Copyright 2002 Fairchild Semiconductor